

DATE: Wednesday, December 11, 2002

Set Name side by side	Query	Hit Count	Set Name result set
•	SPT; PLUR=YES; OP=ADJ		
L11	L9 and adjust\$ near2 (threshold voltage)	9	L11
L10	L9 and threshold voltage	141	L10
L9	L8 and gate and electrode	172	L9
L8	L7 and (wordline or word-line or word line)	354	L8
L7	L6 and sens\$	406	L7
L6	L5 and cell	465	L6
L5	L4 and first voltage	472	L5
L4	L3 and second voltage	487	L4
L3	L2 and third voltage	524	L3
L2	L1 and (bitline or bit-line or bit line)	20884	L2
L1	memory and data	301327	L1

END OF SEARCH HISTORY

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Search Results - Record(s) 1 through 9 of 9 returned.

☐ 1. Document ID: US 6452858 B1

L11: Entry 1 of 9

File: USPT

Sep 17, 2002

US-PAT-NO: 6452858

DOCUMENT-IDENTIFIER: US 6452858 B1

TITLE: Semiconductor device

DATE-ISSUED: September 17, 2002

INVENTOR-INFORMATION:

NAME

CITY

STATE

ZIP CODE

COUNTRY

Hanzawa; Satoru Sakata; Takeshi Hachioji Kodaira JP JP

US-CL-CURRENT: 365/230.06; 365/226, 365/230.01

Full Title Citation Front Review Classification Date Reference Sequences Attachments Claims KMC
Draw Desc Image

2. Document ID: US 6418050 B2

L11: Entry 2 of 9

File: USPT

Jul 9, 2002

US-PAT-NO: 6418050

DOCUMENT-IDENTIFIER: US 6418050 B2

TITLE: Circuits and methods for a memory cell with a trench plate trench capacitor

and a vertical bipolar read device

DATE-ISSUED: July 9, 2002

INVENTOR-INFORMATION:

NAME

CITY

STATE

ZIP CODE

COUNTRY

Forbes; Leonard

Corvallis

OR

US-CL-CURRENT: 365/177; 365/225.6, 365/230.07

Full Title Citation Front Review Classification Date Reference Sequences Attachments Claims KWC

3. Document ID: US 6411543 B1

L11: Entry 3 of 9

File: USPT

Jun 25, 2002

US-PAT-NO: 6411543

DOCUMENT-IDENTIFIER: US 6411543 B1

TITLE: Dynamic random access memory (RAM), semiconductor storage device, and

semiconductor integrated circuit (IC) device

DATE-ISSUED: June 25, 2002

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Narui; Seiji	Hamura			JР
Nagashima; Osamu	Hamura			JP
Hasegawa; Masatoshi	Ome			JP
Fujisawa; Hiroki	Ome			JP
Miyatake; Shinichi	Ome			JP
Suzuki; Tsuyuki	Akishima			JP
Aoki; Yasunobu	Tachikawa			JP
Takahashi; Tsutom	Tachikawa			JP
Kajigaya; Kazuhiko	Iruma			JP

US-CL-CURRENT: 365/149; 365/226, 365/230.06

Full | Title | Citation | Front | Review | Classification | Date | Reference | Sequences | Attachments | Draw, Desc | Image |

KWIC

4. Document ID: US 6201728 B1

L11: Entry 4 of 9

File: USPT

Mar 13, 2001

US-PAT-NO: 6201728

DOCUMENT-IDENTIFIER: US 6201728 B1

TITLE: Dynamic RAM, semiconductor storage device, and semiconductor integrated

circuit device

DATE-ISSUED: March 13, 2001

INVENTOR-INFORMATION:

NAME	CITY	STATE	ZIP CODE	COUNTRY
Narui; Seiji	Tokyo			JP
Nagashima; Osamu	Tokyo			JP
Hasegawa; Masatoshi	Tokyo			JP
Fujisawa; Hiroki	Tokyo			JР
Miyatake; Shinichi	Tokyo			JP
Suzuki; Tsuyuki	Tokyo			JP
Aoki; Yasunobu	Tokyo			JP
Takahashi; Tsutom	Tokyo			JP
Kajigaya; Kazuhiko	Iruma			JP

US-CL-CURRENT: 365/149; 257/E27.085, 365/226, 365/230.06

KWC

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☐ 5. Document ID: US 6011725 A

L11: Entry 5 of 9

File: USPT

Jan 4, 2000

US-PAT-NO: 6011725

DOCUMENT-IDENTIFIER: US 6011725 A

TITLE: Two bit non-volatile electrically erasable and programmable semiconductor

memory cell utilizing asymmetrical charge trapping

DATE-ISSUED: January 4, 2000

INVENTOR-INFORMATION:

NAME

CITY

STATE

ZIP CODE

COUNTRY

Eitan; Boaz

Ra'anana

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m IL}$

US-CL-CURRENT: 365/185.33; 257/E29.308, 365/131, 365/185.29

Full Title Citation Front Review Classification Date Reference Sequences Attachments

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KWC

6. Document ID: US 5881014 A

L11: Entry 6 of 9

File: USPT

Mar 9, 1999

US-PAT-NO: 5881014

DOCUMENT-IDENTIFIER: US 5881014 A

TITLE: Semiconductor memory device with a voltage down converter stably generating

an internal down-converter voltage

DATE-ISSUED: March 9, 1999

INVENTOR-INFORMATION:

NAME

CITY

STATE

ZIP CODE

COUNTRY

Ooishi; Tsukasa

Hyogo

JΡ

US-CL-CURRENT: 365/226; 327/536, 365/189.09, 365/227

Full Title Citation Front Review Classification Date Reference Sequences Attachments

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KWC

7. Document ID: US 5781467 A

L11: Entry 7 of 9

File: USPT

Jul 14, 1998

US-PAT-NO: 5781467

DOCUMENT-IDENTIFIER: US 57 67 A

TITLE: Decoding method for ROM matrix having a silicon controlled rectifier

structure

DATE-ISSUED: July 14, 1998

INVENTOR-INFORMATION:

NAME

CITY

STATE

ZIP CODE

COUNTRY

Wen; Jemmy

Hsinchu City

TW

US-CL-CURRENT: 365/103; 365/174

Full Title Citation Front Review Classification Date Reference Sequences Attachments

KWIC

8. Document ID: US 5742543 A

L11: Entry 8 of 9

File: USPT

Apr 21, 1998

US-PAT-NO: 5742543

DOCUMENT-IDENTIFIER: US 5742543 A

TITLE: Flash memory device having a page mode of operation

DATE-ISSUED: April 21, 1998

INVENTOR-INFORMATION:

NAME

CITY

STATE

ZIP CODE

COUNTRY

Fazio; Albert

Los Gatos

CA

US-CL-CURRENT: 365/185.21; 365/185.03, 365/185.12, 365/185.13, 365/185.26

Full Title Citation Front Review Classification Date Reference Sequences Attachments

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KWIC

9. Document ID: US 5408429 A

L11: Entry 9 of 9

File: USPT

Apr 18, 1995

US-PAT-NO: 5408429

DOCUMENT-IDENTIFIER: US 5408429 A

TITLE: Method of altering a non-volatile semiconductor memory device

DATE-ISSUED: April 18, 1995

INVENTOR-INFORMATION:

NAME CITY

STATE

ZIP CODE

COUNTRY

Sawada; Kikuzo

Sagamihara

JР

US-CL-CURRENT: 365/185.12; 365/185.18, 365/185.26, 365/185.27, 365/185.33